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#### A bstract

There is growing evidence that electronic and molecular networks present some common universal properties, among which the existence of a self-organized intermediate phase. In glasses, the latter is revealed by the reversibility window obtained from complex calorimetric measurements at the glass transition. Here we focus on amorphous networks and we show how this intermediate phase can be understood from a rigidity percolation analysis on size increasing clusters. This provides benchmarks and guidance for an electromechanical analogy with high temperature super conductors.

## 1 Introduction

In the recent years, m ore and m ore studies devoted to the understanding of the m etalinsulator transition (MII) have stressed the possible existence of a self-organized electronic phase [1, 3] that may explain the superconducting state. In these studies, in addition to the prediction or the measurement of a critical dopant concentration  $n_{cl}$ , it is noteworthy to stress that although the mobile charge carrier concentration should tend to zero at the M II and therefore also the interaction between the carriers, the tem perature  $T_c$  should tend to zero, in contrast with current observation. M oreover, a second anom alous behavior is observed at a concentration  $n_{c2}$  from the superconductive phase to the non-superconductive Ferm i liquid. This second transition is much more abrupt and seems rst order in character[4]. Illustrative examples of these behaviors can be found in LSCO ( $La_2 xSr_xCuO_4$ ) from measurements of the lling factors by M eissner volume (i.e. m easuring the fraction of the m aterial that is super conductive) and the transition temperature  $T_c(x)$  with respect to Sr concentration [5]. The nature of this intermediate phase in the dopant region  $n_{c1} < n < n_{c2}$  therefore still needs to be understood. However, beyond the details of modelling [6], a general consensus emerge, which puts forward the idea of the form ation of modulated spatial patterns of m esoscopic length scale as being responsable for HTSC[3, 6].

M uch more simpler examples of self-organization and the existence of an interm ediate phase can be provided by network glasses[7]. Here, instead of following the concentration of m obile carriers, focus is made on elastic deformations of an amorphous network. Thus, instead of M II, percolative sti ness transitions[8] are obtained upon changing the number of possible deformations which in turn can be related to the connectivity of the molecular network. In order to describe these deformations, one simple and elegant idea is to translate the covalent interatom ic valence forces of the atom s in bond-stretching  $n_{\rm c}$  and bond-bending mechanical constraints  $n_{\rm c}$  , using (mean-eld) Maxwell constraint counting [9]. A very particular point is reached when the number of mechanical constraints  $n_c = n_c + n_c$  per atom equals the degrees of freedom per atom in 3D, i.e.  $n_c = 3$  (corresponding to optimal glass formation) [10]. This result has been obtained independently from rigidity percolation by Thorpe[11] on disordered networks, showing that the number of zero frequency solutions (oppy modes) fof the dynamical matrix of the network equals f = 3 n. The enumeration of constraints has been performed on a network of N atom s composed of nr atom s that are r-fold coordinated yielding  $n_c = r=2$  bond-stretching constraints and  $n_c = 2r$ 3 bond-bending constraints for a r-fold coordinated atom . The vanishing of the number of oppy modes is obtained when the mean coordination number of the network reaches the critical value of 2.4, identi ed with an elastic sti ness transition [12]. This point de nes the transition between a oppy network which can be deformed without any cost in energy and a stressed rigid network which has more constraints than degrees of freedom. At the mean coordination number of 2.4, the network is isostatic. This new phase transition has been studied with considerable success in chalcogenides both in experim ents and num erical sim ulations [13]. A pplications of rigidity theory have also been reported in various elds such as granular matter, biology and computational science [14]. However, in the more recent years it has been shown that there should be two transitions[15] instead of the previously reported single transition suggesting that the mean-eld constraint counting alone may be insu cient to describe completely the network change. Results on Ram an scattering and measurem ents of the kinetics of the glass transition using m odulated di erential scanning calorim etry (MDSC) have indeed provided evidence [15, 16] for two vibrational thresholds thus de ning a stress-free interm ediate phase (isostatically rigid) in between the oppy and the stressed rigid phases, for which independent evidence is obtained from num erical simulations[17].

In this paper, we will construct a system atic approach that enables us to perform constraint counting on size increasing structures thus permitting to take into account medium range order elects such as small rings. In doing this, we show that these small rings mostly control the values of the critical coordination numbers and the width of the intermediate phase. The construction will also show how isostatic regions and self-organization in uence the absolute magnitude of the width. The simplest case that can be build up corresponds to G roup IV chalcogenide glasses of the form  $B_xA_{1-x}$  with coordination numbers  $r_A = 2$  and  $r_B = 4$  defining the mean coordination number r = 2 + 2x. Size-increasing cluster approximations (SICA) have been used in order to generate medium range order (MRO) from sets of clusters on which we have realized constraint counting. The results show two transitions. A first one at which the number of oppy modes vanishes and a second one (a \stress transition") beyond which stress in the structure can not be avoided anym ore out of ring structures. In between, this

de nes an alm ost stress-free network structure for which the rate of isostatic regions can be computed. We will extend these results on solid electrolytes for which percolative conductivity should be detected.

# 2 Size increasing cluster approxim ations and constraint counting

Size increasing cluster approximations (SICA) have been stintroduced to describe the m edium and interm ediate range order in am orphous sem i-conductors[18] but their usefulness has been also stressed for the description of the form ation of quasi-crystals[19] and fullerenes[20]. This approach em phasizes the rapid convergence of signi cant M RO structures to a lim it value when the size of the considered clusters is increasing. Ideally, the in nite size cluster distribution would yield the exact statistics of MRO in the structure. The construction of these clusters is realized in Canonical Ensemble with particular energy levels corresponding to bond creation between short range order molecules (basic units) which are used as building blocks from step  $\models 1$  (corresponding here to the reported m ean- eld approach [9]) to arbitrary 1. This construction should be realized at the form ation of the network, when T equals the ctive tem perature  $T_f$  [21]. Since we expect to relate the width of the interm ediate phase with the ring fraction, we will restrict our present study to G roup IV chalcogenides of the form  $Si_xSe_1$ . For the latter, there is strong evidence that at the stoichiom etric concentration x=0.33 a substantial amount of edge-sharing S is  $e_{4=2}$  tetrahedra [22] can be found. Therefore, we select basic units such as the  $A_2$  (i.e.  $Se_2$ ) chain fragment and the stoichiom etric  $BA_{4=2}$  molecule (e.g. SiSe<sub>4=2</sub>). These basic units have respective probabilities 1 р x), x being the concentration of the G roup IV atom s. W e associate and p = 2x = (1)the creation of a chain-like  $A_2$   $A_2$  structure (see Table I) with an energy state of  $E_1$ , isostatic  $A_2$   $B_2$  bondings with an energy gain of  $E_2$  and corner-sharing (CS) and edge-sharing (ES)  $BA_{4=2}$  tetrahedra or any ring structure respectively with  $E_3$  and  $E_4$ . The probabilities of the di erent clusters have statistical weights  $q(E_i)$  which can be regarded as the degeneracy of the corresponding energy level and correspond to the num ber of equivalent ways a cluster can be constructed. Examples of statistical weights for the step l = 2 are shown in Table I and in Refs[18, 19].

Due to the initial choice of the basic units, the energy  $E_2$  will mostly determ ine the probability of isostatic clusters since this quantity is involved in the probability of creating the isostatic  $BA_4$  cluster (a  $A_2$   $BA_{4=2}$  bonding). As a consequence, if we have  $E_2$   $E_1; E_3; E_4$ , the network will be mainly isostatic in the range of interest.

The calculation of the number of bond-bending  $n_c$  and bond-stretching mechanical constraints  $n_c$  per atom is performed on each cluster by M axwell counting and redundant constraints in ring structures are removed following the procedure described by Thorpe[11]. It is obvious from the construction that all the cluster probabilities will depend only on two parameters (i.e. the factors  $e_1=e_2$  and  $e_3=e_2$ ) and eventually  $e_4=e_2$ 

if one considers the possibility of edge-sharing (ES) tetrahedra or rings. One of the two factors has to be composition dependent since a conservation law for the concentration of B atom s  $x^{(1)}$  has to be full led at any step l of the construction [23]:

$$\mathbf{x}^{(1)} = \mathbf{x} \tag{1}$$

This means that either the ctive temperature  $T_f$  or the energies  $E_i$  depend on x [21] but here only the  $e_i(x)$  dependence is relevant for our purpose. O focurse, when the step lw ill increase, the number of isom ers will also increase among those also the number of di erent types of rings. The construction has been realized up to the step l = 4 which already creates clusters of MRO size. For each step l, we have determined either  $e_1 = e_2$  or  $e_3 = e_2$  solving equ. (1) and computed the total number of constraints  $n_c^1$ :

$$n_{c}^{1} = \frac{\frac{P_{N_{1}}}{\sum_{i=1}^{N_{1}} n_{c(i)} p_{i}}}{\frac{P_{N_{1}}}{\sum_{i=1}^{N_{1}} N_{i} p_{i}}}$$
(2)

where  $n_{c(i)}$  and N<sub>i</sub> are respectively the number of constraints and the number of atom s of the cluster of size lw ith probability  $p_i$ . Once the factors become composition dependent, it is possible to nd for which concentration x (or which mean coordination number r) the system reaches optim alglass form ation where the number of oppy modes f = 3  $n_c^1$  vanishes.

#### 3 Results

Various possibilities can be studied within this fram ework. The simplest case which can be investigated at the very beginning is the random bonding case which is obtained when the cluster probabilities  $p_i$  are only given by their statistical weights (in other words, the factors  $e_i$  are set to one). A single solution is obtained for the glass optimum point de ned by f = 0 at all SICA steps, in the mean coordination number range [2.231,2.275], slightly lower than the usual mean-eld value of 2.4. Since there is only one solution, no intermediate phase in the case of random bonding is found.

Self-organization can be obtained by starting from a oppy cluster of size 1 (e.g. a chain-like structure m ade of a majority of A atom s), and allowing the agglom eration of a new basic unit onto this cluster to generate the cluster of size 1+1 only if the creation of a stressed rigid region can be avoided on this new cluster. The latter occurs when two B A<sub>4=2</sub> basic units are joined together. W ith this rather sin ple rule, upon increasing r one accumulates isostatic rigid regions on the size increasing clusters because B A<sub>4=2</sub> units are only accepted in A<sub>2</sub> B A<sub>4=2</sub> isostatic bondings with energy E<sub>2</sub>. A Itematively, we can start from a stressed rigid regions, excluding system atically the possibility of oppy A<sub>2</sub> A<sub>2</sub> bondings. In the case of self-organized clusters, the sin plest case to be studied is the case of dendritic clusters, when ring creation is avoided. For an in nite size 1, this would perm it to recover the results from B ethe lattice solutions or R andom

Bond M odels[24] for which rings are also excluded in the therm odynam ic lim it [25]. A single transition for even 1 steps at exactly the mean-eld value r = 2:4 is obtained whereas for the step l = 3, there is a sharp intermediate phase de ned by f = 0 (still at r = 2:4) and the vanishing of oppy regions (i.e.  $e_1=e_2$  is zero) at r = 2:382 (6). The probability of oppy, isostatic rigid and stressed rigid clusters as a function of the mean coordination number has been computed and shows that the network is entirely isostatic at the point where f = 0 (solid line, g. 1).

The intermediate phase shows up if a certain amount of medium range order (MRO) is allowed. This is realized in the SICA construction by setting the quantity  $e_4 = e_2$  non zero, i.e. edge-sharing (ES) tetrahedra  $BA_{4=2}$  leading to four-m embered rings  $B_2A_4$  can now be created at the growing cluster steps. Two transitions are now obtained for every SICA step. The rst one is still located at  $r_{cl} = 2.4$  (see g. 1). There, the number of oppy modes f vanishes. The second one is located at  $r_{c2}$ . When starting from a oppy network close to r = 2 and requiring self-organization (in this case, allowing only oppy or isostatic bondings), this point corresponds to the network composition beyond which stressed rigid regions outside of ring structures, which are created by the dendritic connection of at least two  $BA_{4=2}$  units can not be avoided anym ore. We call this point the \stress transition". We show in g. 1 the l = 2 result where f = 0 at  $r_{c1} = 2.4$  for di erent fractions of ES tetrahedra, de ning an intermediate phase r. It is noteworthy to stress that the rst transition at  $r_{cl}$  corresponding to Phillips' glass optimum does not depend on the ES fraction, as well as the fraction of stressed rigid clusters in the structure. To ensure continuous deform ation of the network when B atom s are added and keeping the sum of the probability of oppy, isostatic rigid and stressed rigid clusters equal to one, the probability of isostatic rigid clusters connects the isostatic solid line at  $r_{c2}$ . Stressed rigid rings is appear in the region  $r_{c1} < r < r_{c2}$ while chain-like stressed clusters (whose probability is proportional to  $e_3$ ) occur only beyond the stress transition, when  $e_3 \in 0$ . This means that within this approach, when r is increased, stressed rigidity nucleates through the network starting from rings, as ES tetrahedra. It appears from q. 1 that the width  $r = r_{c2}$   $r_1$  of the interm ediate phase increases with the fraction of ES. We have represented the width as a function of the overall MRO fraction at the rigidity transition in g. 2 which shows that r is almost an increasing function of the ES fraction as seen from the result at SICA step 1= 4. Here, there is only a small di erence between allowing only four-membered rings (ES) (lower dotted line) or rings of all sizes (upper dotted line) in the clusters. Concerning the nature of the structure in the intermediate phase, one can see from g. 1 and the insert of g. 2 that the probability of isostatic clusters is maximum in the window r, and alm ost equal to 1 for the even SICA steps, providing evidence that the m olecular structure in the window is alm ost stress-free. Furtherm ore, the latter can be extremely broad if a high amount of edge-sharing is allowed. For a fraction of ES is close to one, molecular stripes emerge in the structure which are isostatic and every addition of new B atom s lowers the amount of remaining A -chains by converting them in ESBA  $_{4=2}$  stripes. These molecular stripes are stress-free only if their size is in nite

[11], which is the case for '1 in the therm odynam ic lim it.

## 4 Application to chalcogenides

A sm entioned above, chalcogenide glasses are the rst system swhich have been carefully studied in the context of self-organization. SICA provides therefore a benchm ark to check the results obtained. To be specic, Ram an scattering has been used [27, 28] as a probe to detect elastic thresholds in binary  $Si_xSe_1 \times and Ge_xSe_1 \times or$  ternary  $Ge_xAs_xSe_{1-2x}$  glasses[29]. Changes in the germanium or silicon corner sharing mode chain frequencies have been studied with mean coordination number r of the glass network. These frequencies exhibit a change in slope at the mean coordination number  $r_{c1} = 2.4$  and a rst order jump at the second transition  $r_{c2}$ . In germanium systems, the second transition is located around the mean coordination number of 2:52 whereas  $r_{c2} = 2.54$  in Sibased systems. For both systems, a power-law behavior in r  $\mathbf{r}_2$ is detected for  $r > r_{c2}$  and the corresponding measured exponent is very close to the one obtained in num erical sim ulations of stressed rigid networks [26]. M oereover, a clear correlation between these results and the vanishing of the non-reversing heat ow H  $_{\rm nr}$ (the part of the heat ow which is therm all history sensitive) in MDSC measurements has been show n[27, 28].

The SICA approach shows that the width r of the interm ediate phase increases mostly with the fraction of ES tetrahedra. We stress that the width should converge to a lower limit value of r compared to the step l = 2, therefore one can observe the shift downwards when increasing 1 from 2 to 4. This limit value is in principle attained for l! 1, or at least form uch larger steps than l = 4 [30]. For Si-Se, r = 0.14 is som ew hat larger than for Ge-Se (r = 0.12) consistently with the fact that the number of ES is higher in the form er[28].

## 5 Application to solid electrolytes

O ne interesting eld of application of cluster construction and constraint counting algorithm s is the area of fast ionic conductors (FIC) [31, 32], which has recently gained attention because of potential applications of these solid electrolytes in all solid state electrochem ical devices and/orm iniaturized system s such as solid state batteries. This has been m ade possible by substitution of more polarizable sulfur atom s, replacing the oxygen in usual oxide glasses and has led to a substantial increase of the conductivity [33], as high as 10<sup>-3</sup> m<sup>-1</sup>, three orders of magnitude higher than the conductivity of analogous oxide glasses[34]. Surprisingly, the extension of constraint theory from network glasses (as S i<sub>x</sub>Se<sub>1-x</sub>) to FIC has been only reported for a few oxide glasses[35, 36]. As a consequence, percolative e ects have not been studied so far with the network change in FIC, although it seems fundamental for the understanding of the mobile alkali cations' motion. Since the conductivity of the sem i-conductor is proportional to

the mobility , which in turn is related to the deform ation of the network [37], and the free carrier concentration  $n_L$  by  $= n_L e$ , one may expect that the mobility in a oppy FIC should be substantially higher compared to the cation mobility in a stressed rigid network. This means that the conductivity should display some particular behavior in the stress-free intermediate phase and at the two transitions.

O ne can extend the SICA approach to the present case by considering the simplest binary conducting glass, which is of the form  $(1 \ x)SiX_2 \ xM_2X$  with X an atom of G roup VI (X = 0, S,Se) and M an alkali cation (M = Li<sub>1</sub>N a,K,...). The local structure can be obtained from NM R m easurements and is mainly made of so-called Q<sup>3</sup> and Q<sup>4</sup> units[38]. The former corresponds to the usual silica tetrahedron made of one silicon and four G roup VI atoms at the corner [e.g. SiSe<sub>4=2</sub>] while the latter has one oxygen atom ionically bonded to the alkali cation [e.g. SiSe<sub>5=2</sub>N a ] (g. 3).

Then, the probabilities can be evaluated for di erent steps of cluster sizes following the procedure described in the previous sections. It appears that the creation of a  ${\rm Q}^4$  connection leads to a stressed rigid cluster if the number of constraints is  $O^4$ computed, while the  $Q^4$   $Q^3$  and  $Q^3$   $Q^3$  connections yield respectively isostatically stressed and oppy clusters. The SICA results show again that the interm ediate phase shows up if a non-zero fraction of small rings is allowed in the structure, as displayed in q. 4. Here in contrast with chalcogenides, the glass optimum correponding to the vanishing of the number of oppy modes respresents the upper lim it of the intermediate phase, which is consistent with the fact that one starts from an almost stressed rigid m olecular network at low m odi er concentration. Increase of the alkali content leads to an increase of oppiness. In the oxide system  $(1 \ x)$ SiO<sub>2</sub> xM<sub>2</sub>O, the width x should be very small or zero since the fraction of ES in the oxide systems is almost zero [21]. Still, percolative e ects are expected at the concentration x = 0.2 corresponding to the transition from rigid to oppy networks. In sulfur and selenide glasses such as xN a,S, the width should be much broader because of the existence (1 x)SiS of a high amount of edge-sharing tetrahedra in the  $SiS_2$  or  $SiSe_2$  base networks[39]. In the sulfur base glass, <sup>29</sup>SiNMR have shown that the rate of ES should be about 0.5, slightly higher than in the selenide analogous system [40]. As a result, one should observe a window of about x = 0.09. Unfortunately, results on these systems are only available for an alkali concentration x > 0.2 [41]. However, in the di erent silica based glasses, a rigidity transition has been observed [42] at the concentration x = 0.2 which should provide guidance for forthcom ing studies in this area.

Finally, temperature e ects should be observable close to this transition. Since the concentration of alkali free carriers  $n_L$  depends on the temperature (the higher the temperature, the higher  $n_L$ ), an increase of the temperature T should lead to a decrease of the number of network constraints, the fraction of intact bond-stretching constraints  $n_c$  of the alkali atom being proportional to 1  $n_L$ . Consequently, a shift of the mechnical threshold (f = 0) to the higher concentrations should result from an increase of T.

## 6 Summary

In this article, we have shown how stress change in m olecular system s can be understood from the combination of cluster construction and constraint counting. We have found that there is a single transition from oppy to rigid networks in a certain number of structural possibilities. An intermediate phase intervenes when a fraction of non-zero molecular isostatic stripes are allowed, which makes this new phase globally stress-free. The similarity of this new phase with the superconducting lamentary phase in HTSC [3] but also in biological networks[14] is striking and should be worked out in more depth in the future.

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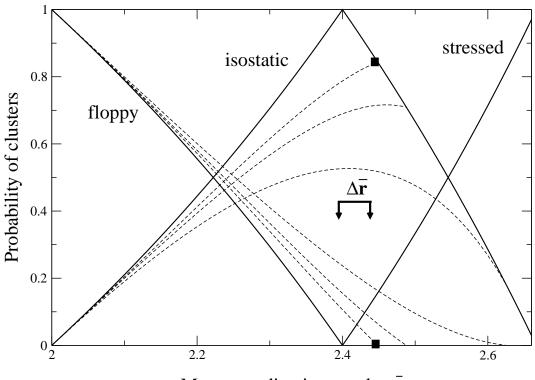
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symbol	m echanical nature		probability	n <sub>c</sub>
			4.41	2.0
A 4	орру		4(1 p) <sup>2</sup> e <sub>1</sub>	2.0
			160 (1	2.0
BA <sub>4</sub>	isostatic	0	16p(1 p)ę	3.0
B 2A 4	stressed	Ь	16p²e <sub>3</sub>	3.67
			2	
B <sub>2</sub> A <sub>4</sub>	stressed	$\bigcirc$	72p <sup>2</sup> e <sub>4</sub>	3.33

Table 1: The four clusters generated at step l = 2 with their unrenormalized probabilities and their number of mechanical constraints. The factors  $e_i$  are Boltzm ann factors involving bond energies and the clive temperature,  $e_i = \exp[E_i = T_f]$ 



Mean coordination number  $\bar{\textbf{r}}$ 

Figure 1: P robability of nding oppy, isostatic rigid and stressed rigid clusters as a function of m ean coordination number r at SICA step l = 2 for di erent fractions of edge-sharing. The solid line corresponds to the dendritic case where no rings are allowed ( $e_4 = 0$ ). The broken lines correspond to situations whith a fraction of ES at the stress transition of = 0.156, 0.290 and 0.818. The led squares indicate the point  $r_{c2}$  at which the stress transition occurs in the case = 0.156.

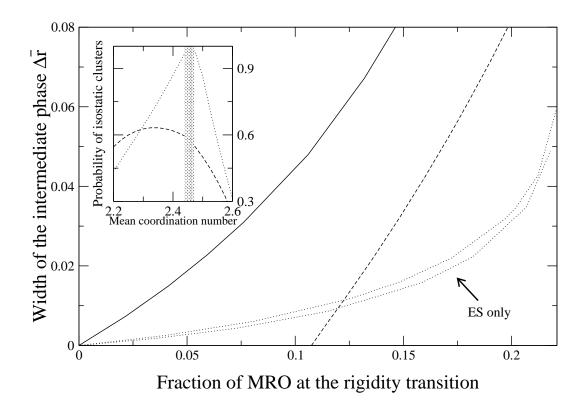


Figure 2: W idth of the interm ediate phase r as a function of the fraction of ring clusters at the rigidity transition for l = 2 (solid line), l = 3 (dashed line) and l = 4 (dotted lines). At step l = 2, the non-zero width comes only from the edge-sharing BA<sub>4=2</sub> tetrahedra. For l > 2, di erent rings sizes (4;6;8) have been taken into account. The lower dotted line corresponds to the interm ediate phase at l = 4 if only ES are allowed as stressed rigid fragments. The upper dotted line is the same equantity but allowing any ring structure. The insert shows the probability of isostatic clusters with mean coordination number r for l = 4 (dotted line) and l = 3 (dashed line). The shaded region of l = 4 represents the interm ediate phase.

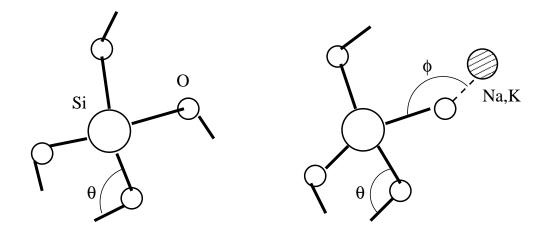


Figure 3: The two local structures of the fast ionic conducting  $(1 \ x)SiX_2 \ xM_2X$ , (X = 0;S;Se;M = Li;Na;K) glasses, denoted as  $Q^4$  and  $Q^3$  units, with respective probabilities 1 p and  $p = 2x = (1 \ x)$ .

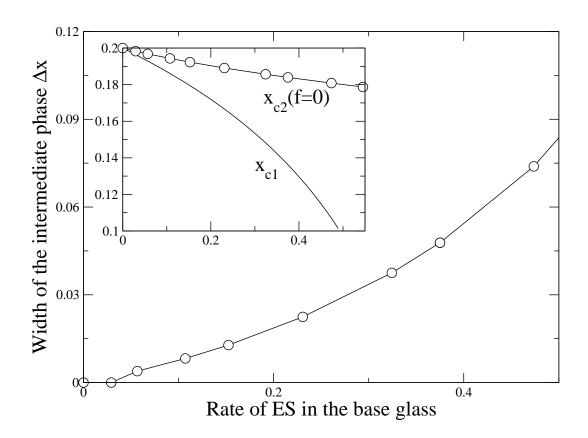


Figure 4:W idth of the interm ediate phase x as a function of the rate of edge-sharing (ES) in the base glass. The insert shows the solutions  $x_{c1}$  and  $x_{c2}$  obtained from SICA analyis, again as a function of ES.